

# GEN series CTS200ID

200 A RMS / 300 A DC Current Transducer

## **Special features**

- 200 A RMS nominal current
- 300 A DC nominal current
- 500 kHz bandwidth (-3 dB)
- 27.6 mm aperture for cables and bus bars
- -40 °C to +85 °C operating range
- Best in class for accuracy and stability
- Isolated AC and DC current measurements
- 2 ppm maximum linearity error
- Industry standard D-SUB 9 connector
- Full aluminum body for superior EMI shielding
- Advanced sensor protection circuits

#### **GEN series CTS200ID applications**

The HBM series of current transducers feature industry standard, fluxgate, closed-loop technology. The second harmonic zero flux detection ensures the highest accuracy and lowest drift while maintaining a high bandwidth. HBM current transducers are perfect for measuring currents between 10 and 1000 A RMS. With the high bandwidth support, they can be used with fast rise time signals, such as those found in electric drives or other inverter applications, such as those in renewable industries.

The CT series is available for 50 A RMS to 1200 A RMS, all sharing the same high-end technology. All connectors are compatible for fast exchange.

The optional 1 HE 19" rack mountable power supply can power any mix of up to six CTs. Current output cables to connect directly to the GN31XB power card, as well as to the GN61XB card, are available.

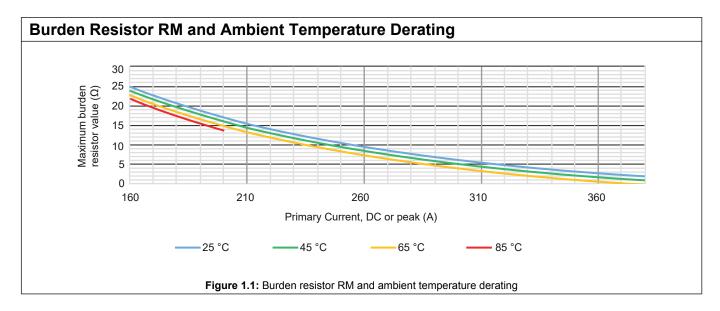
Optional burden resistors are available for the GEN series Data Acquisition Systems or power analyzers without an integrated burden resistor.

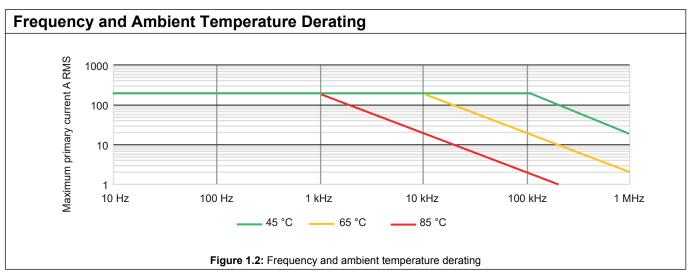
The advanced sensor protection circuit ASPC prevents sensor damage for incorrect use cases, such as currents applied to unpowered CTs or powered CTs without a burden resistor to close the current output loop.

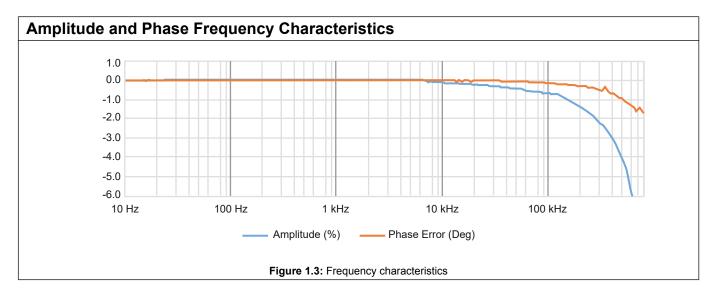


Specification Highlights				
	Symbol	Value	Comment	
Nominal primary AC current	I <sub>PN</sub> AC	200 A RMS		
Nominal primary DC current	I <sub>PN</sub> DC	± 300 A		
Nominal secondary current	I <sub>SN</sub>	± 600 mA	At nominal primary DC current	
Primary / secondary ratio	n1 : n2	1:500		
Measurement range	Î <sub>PM</sub>	± 370 A		
Measurement resistance	R <sub>M</sub>	3 Ω maximum	See Figure 1.1 for details	
Bandwidth	f(-3dB)	500 kHz	Small signal, refer to Figure 1.3	

Electrical Specifications					
At Ta = 23 °C, supply voltage = ± 15 V unless otherwise stated					
Parameter		Symbol	Value	Comment	
Overload capacity		Î <sub>OL</sub>	± 1500 A for 100 ms	Non-measured, 100 ms	
Linearity error		$\mathcal{E}_{L}$	± 2 ppm	Refers to nominal DC current	
Offset current (including ea	arth field)	I <sub>OE</sub>	± 20 ppm	Refers to nominal DC current	
DC -10 Hz overall accuracy (= £L + I <sub>OE</sub> )	y @ 25 °C	acc8	± 22 ppm	Refers to nominal DC current	
Offset temperature coeffici	ent	TC <sub>IOE</sub>	± 0.1 ppm/K	Refers to nominal DC current	
	10 Hz - 5 kHz		± 0.01%		
Amplitude error	5 kHz - 100 kHz	EG	± 1.00%	Refers to nominal current	
	100 kHz - 1 MHz		± 20.00%		
	10 Hz - 5 kHz		± 0.1°		
Phase shift	5 kHz -100 kHz	θ	± 0.5°		
	100 kHz - 1 MHz		± 5.0°		
Response time to a step cu	urrent IPN	tr @ 90%	1	di/dt = 100A/μs	
	0 - 100 Hz		0.02 ppm RMS		
Noise	0 - 1 kHz	noise	0.04 ppm RMS	Measured on secondary current	
NOISE	0 - 10 kHz		0.40 ppm RMS	Measured on secondary current	
	0 - 100 kHz		1.50 ppm RMS		
Fluxgate excitation frequer	псу	f <sub>Exc</sub>	32.5 kHz		
Induced RMS voltage on p	rimary conductor		5 μV RMS		
Stability					
Offset stability over time			± 0.2 ppm/month	Refers to nominal DC current	
Offset change with vertical field	external magnetic		± 2.4 μA /mT (± 0.6 μA /mT typical)	(Perpendicular to bus bar) μA refers to secondary current	
Offset change with horizon field	tal external magnetic		± 6 μA /mT (± 2.4 μA /mT typical)	(Perpendicular to bus bar) μA refers to secondary current	
Offset change with power supply voltage changes			± 0.12 μA /V (± 0.012 μA /V typical)	μA refers to secondary current	
Offset change with absolute power supply voltages tracking			± 0.12 μA /V (± 0.036 μA /V typical)	μA refers to secondary current	
Power supply		•	•	•	
Power supply voltages		Uc	15 V ± 0.75 V DC		
Positive current consumption	on	lps	104 mA + Is	Add Is (if Is is positive)	
Negative current consumpt	tion	Ins	96 mA + Is	Add Is (if Is is negative)	







Isolation Specifications						
Clearance	9 mm					
Creepage distance	10 mm					
Comparative tracking index (CTI)	> 600 V					
RMS voltage for AC isolation test, 50/60 Hz, 1 mir	1					
Between primary and (secondary and shield)	5.7 kV					
Between secondary and shield	0.2 kV					
Impulse withstand voltage (1.2/50 µs)	10.4 kV					
Continuous working voltage	Using uninsulated wire	Using insulated wire				
Continuous working voltage  Non mains signals	Using uninsulated wire 1000 V	Using insulated wire 2000 V				
<u> </u>		_				
Non mains signals	1000 V	2000 V				
Non mains signals  CAT II signals	1000 V 600 V RMS / 600 V DC	2000 V 1000 V RMS / 1000 V DC				
Non mains signals  CAT II signals  CAT III signals	1000 V 600 V RMS / 600 V DC 300 V RMS / 300 V DC	2000 V 1000 V RMS / 1000 V DC 1000 V RMS / 1000 V DC				
Non mains signals  CAT II signals  CAT III signals  Transient voltage	1000 V 600 V RMS / 600 V DC 300 V RMS / 300 V DC Using uninsulated wire	2000 V 1000 V RMS / 1000 V DC 1000 V RMS / 1000 V DC Using insulated wire				

Note Higher isolation voltages can be achieved using isolated bus bars. Contact custom systems at: <a href="mailto:customsystems@hbm.com">customsystems@hbm.com</a>.

Environmental and Safety Specifications				
Ambient operating temperature range	-40 °C to +85 °C			
Storage temperature range	-40 °C to +85 °C			
Relative humidity	20% to 80%, Non-condensing			
Maximum altitude	2000 m (6562 ft)			
Harmonized standards for CE compliance	EN 61326-1 EMC EN 61010-1:2010 Safety IEC61010-2-30			
External devices	External devices connected to current transducers must comply with the standards IEC61010-1, IEC60950 or IEC62368-1 and be energy-limited circuitry			
Cleaning	The transducer should only be cleaned with a damp cloth. No detergent or chemicals should be used.			
Ambient Temperature	Note: When multiple primary turns are used or high primary currents are applied the temperature around the transducer will increase, please monitor to ensure that the maximum ratings are not exceeded.  It is recommended to have minimum 1mm² per ampere in the primary bus-bar.			

## **Advanced Sensor Protection Circuits (ASPC)**

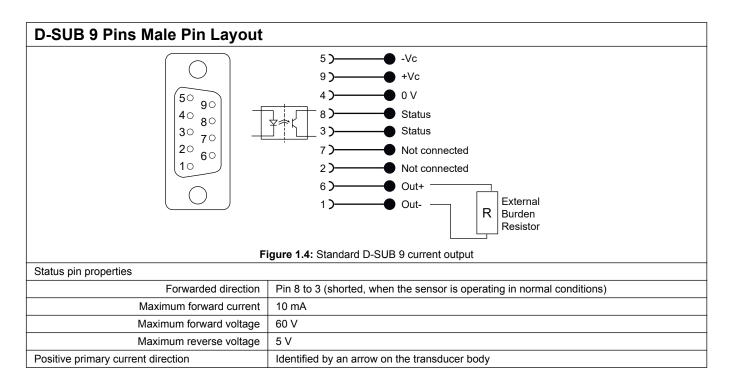
Developed to protect the current transducer from typical fault conditions

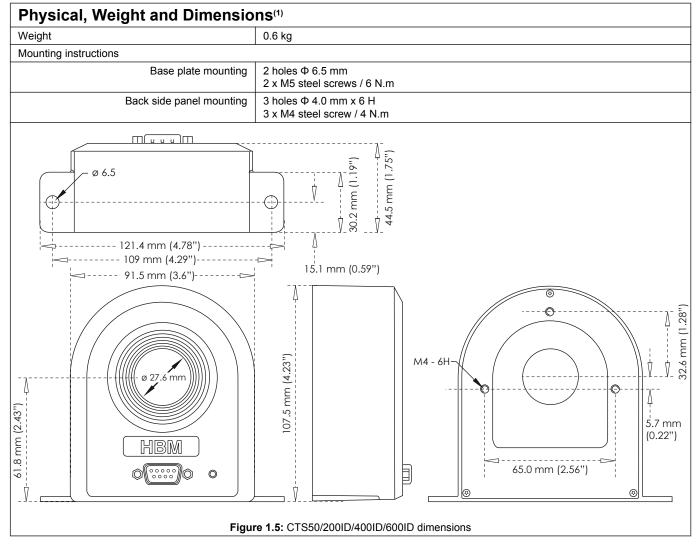
- Unit is unpowered and secondary circuit is open or closed
- Unit is powered and secondary circuit is open or interrupted

Both DC and AC primary current up to 100% of nominal value can be applied to the current transducers in the situations above without damage to the electronics

Note The sensor core can be magnetized in all the cases above, resulting in a small change in output offset current (less than 10 ppm)

Korean Certification	
	상호 : 스펙트리스코리아주식회사
	기자재명칭(모델명) : 1-CTS200ID/Current transducer (CTS200ID)
	제조자 : Hottinger Brüel & Kjaer GmbH, Germany
	제조국가 : 덴마크
	R-R-s3k- CTS200ID



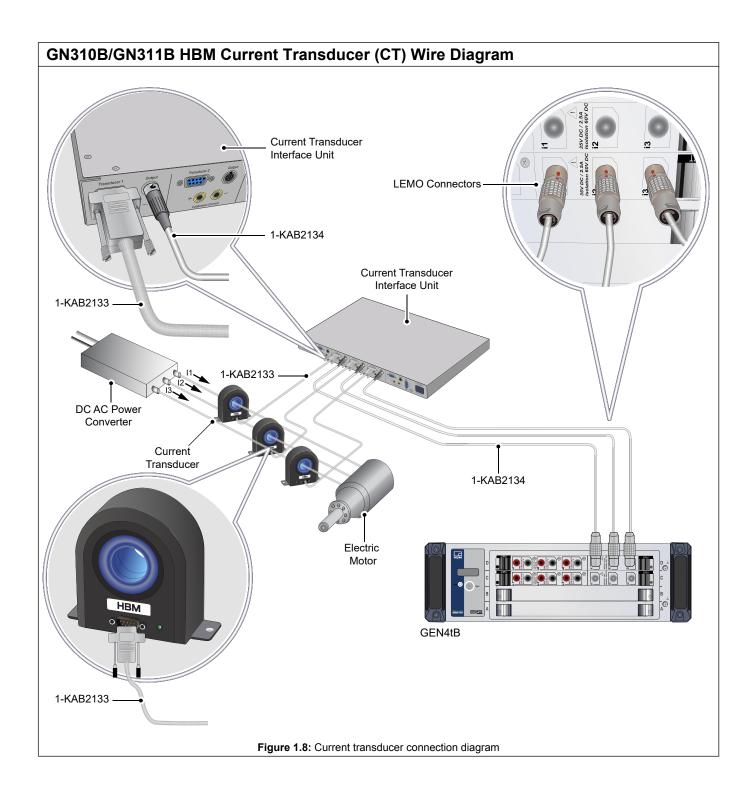


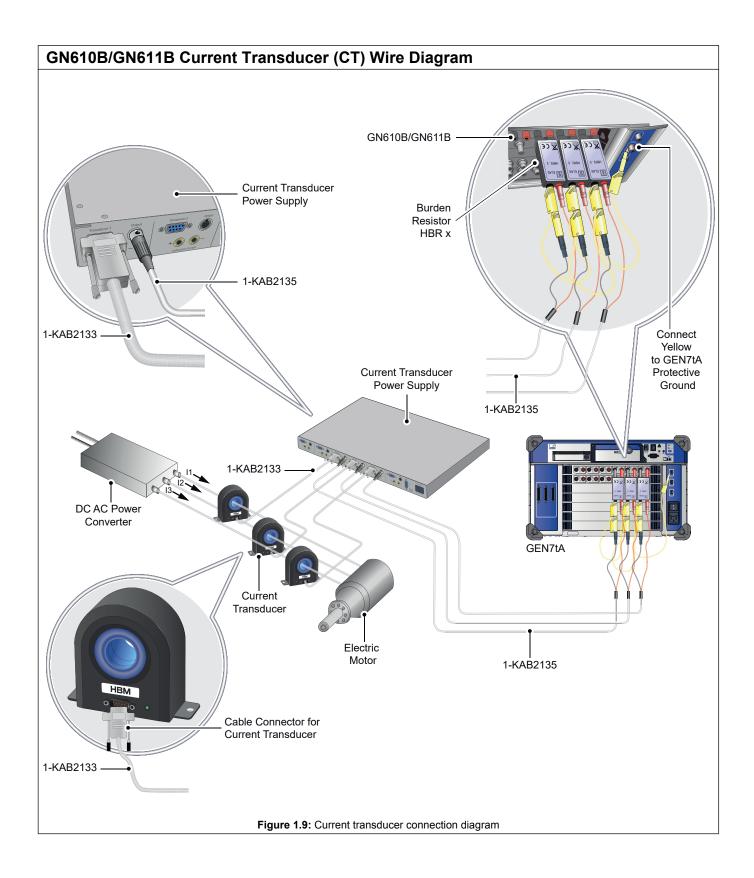
(1) General tolerance of 0.3 mm unless otherwise stated

1-CTPSIU-6-1U Interface Unit for CT (Option, to be ordered separately)				
Modular 19" rack with 1 to maximum 6 channel C	T support.			
- HBM	CTPS61  Qure 1.6: Front side (left) and rear side (right)			
Maximum number of CTs	6			
Input connectors	9 pin SUBD			
Output connectors	XLR			
Signal LEDS	CT Power ON, CT Status			
Power supply	100 to 240 V AC, 47 to 63 Hz 120 - 370 V DC			
Weight	Typical 6.5 kg (14.33 lb)			
Operating temperature range	0 °C to +50 °C (32 °F to 122 °F)			
Dimensions				
Height	87.2 mm (3,43")			
Width / Width including mounting ears	442 mm (17,40") / 466 mm (18,34")			
Depth	415 mm (16,33")			
466 mm (18.3")	442 mm (17.4")			
0	CTPS61 O O O O O O O O O O O O O O O O O O O			
	Figure 1.7: Dimensions			

Туре	Nominal current	Bandwidth (-3 dB)	Ratio Primary : Secundary	Aperture size
CTS50ID	50 A RMS / 75 A DC	1000 kHz	1 : 500	27.6 mm
CTS200ID	200 A RMS / 300 A DC	500 kHz	1 : 500	27.6 mm
CTS400ID	400 A RMS / 600 A DC	300 kHz	1 : 2000	27.6 mm
CTS600ID	600 A RMS / 900 A DC	500 kHz	1 : 1500	27.6 mm
CTM1200ID	1200 A RMS / 1500 A DC	400 kHz	1 : 1500	45.0 mm
CTM1200ID-CD3000 <sup>(1)</sup>	1200 A RMS / 1500 A DC	15 kHz	1 : 1500	45.0 mm

- (1) Support for low current calibration.
- (2) Contact custom systems at: <a href="mailto:customsystems@hbm.com">customsystems@hbm.com</a>
  Request quote/information for special products for GEN series.





Ordering Information				
Article	Description	Order No.		
300 A DC or 200 A RMS current transducer	Ultra-stable, high-precision fluxgate technology current transducer.  Non-intrusive isolated DC and AC current measurement up to 200 A RMS / 300 A DC.  Full aluminum body for superior EMI shielding.  Extended operating temperature range.  Large aperture Ø 27.6 mm for cables and bus bars.  Industry standard D-Sub 9 pin connection.	1-CTS200ID		

Current Tran	Current Transducers Interface and Cables, to be ordered separately				
Article		Description	Order No.		
CT Interface unit	COURT -	Interface unit for up to six current transducers. Industry standard D-SUB 9 pin input connectors. Multi-pin XLR output connectors. Supports transducer calibration winding access through 4 mm banana plugs. Front LEDs to indicate normal operation of each transducer. 100 - 240 V AC 50/60 Hz AC input voltage. 120 - 370 V DC input voltage. 1U height 19" rack mountable.	1-CTPSIU-6-1U		
CT cables		Industry standard current transducer connection cable. Shielded, low ohmic 9 wire cable with D-SUB 9 connectors on both ends. Supports power, status, current output and calibration current input. Lengths: 2, 5, 10 and 20 meters (6, 16, 32 and 65 ft)	1-KAB2133-2 1-KAB2133-5 1-KAB2133-10 1-KAB2133-15 1-KAB2133-20		
XLR to LEMO cable for GN31XB		CT interface unit to GN31xB DAQ power card connection cable. Uses XLR and LEMO connectors for a direct current output connection to the GEN DAQ card.  Length 2 m (6 ft)	1-KAB2134-2		
XLR to Banana cable for GN61XB		CT interface unit to GN61xB DAQ 1kV card connection cable. Uses XLR and banana connectors for a current output connection to the GEN DAQ card. Requires an additional burden resistor in front of the GN61xB card to convert current to voltage.  Length 2 m (6 ft)	1-KAB2135-2		

## GN610B/GN611B Burden Resistors, to be ordered separately

#### Burden selection for GN610B/GN611B

**Note:** When using the CTS/CTM series together with GN610B/GN611B cards a burden resistor is required to convert the CT output current to a voltage. When selecting the burden several specifications need to be taken into account: maximum power of the burden, maximum voltage the CT can drive with constant current, the wire impedance of the cables used etc. See the CT operating manual for more details.

Model	Recommended burden	mV/A sensitivity	A/V scaling
CTS50ID	HBR 2.5 Ω	5.0	200
CTS200ID	HBR 1.0 Ω	2.0	500
CTS400ID	HBR 1.0 Ω	0.5	2000
CTS600ID	HBR 1.0 Ω	0.6667	1500
CTS1200ID	HBR 1.0 Ω	0.6667	1500
CTS1200ID-CD3000	HBR 1.0 Ω	0.6667	1500

CTS1200ID-CD3000	0   HBR 1.0 Ω	0.6667	1500	
Article		Description		Order No.
HBR 0.25 Ω, 1 W precision burden resistor	HARO 35 HERO 3	0.25 Ω1 W, 0.02% high precision, low the resistor. Internally uses 4 wire connection caused by the currents running to the but banana input connectors and banana our compatible with GN610B/GN611B acquisitions.	n to reduce inaccuracy rden resistor. Using tput pins. Directly	Ordered from custom systems <sup>(1)</sup>
HBR $0.5 \Omega$ , 1 W precision burden resistor	MORO, 5	0.5 Ω1 W, 0.02% high precision, low ther resistor. Internally uses 4 wire connection caused by the currents running to the but banana input connectors and banana out compatible with GN610B/GN611B acquisitions.	n to reduce inaccuracy rden resistor. Using tput pins. Directly	Ordered from custom systems <sup>(1)</sup>
HBR 1 $\Omega$ , 1 W precision burden resistor	MINIO TANKIO	$1\Omega$ , $1W$ , $0.02\%$ high precision, low therm. Internally uses 4 wire connection to reduby the currents running to the burden resinput connectors and banana output pins with GN610B/GN611B acquisition cards.	ce inaccuracy caused sistor. Using banana s. Directly compatible	Ordered from custom systems <sup>(1)</sup>
HBR 2.5 $\Omega$ , 1 W precision burden resistor	Mana Mina S	$2.5~\Omega$ , 1 W, 0.02% high precision, low the resistor. Internally uses 4 wire connection caused by the currents running to the bulbanana input connectors and banana our compatible with GN610B/GN611B acquisi	n to reduce inaccuracy rden resistor. Using tput pins. Directly	Ordered from custom systems <sup>(1)</sup>
HBR 10 Ω, 1 W precision burden resistor	NURTO PEROSE	10 Ω, 1 W, 0.02% high precision, low the resistor. Internally uses 4 wire connection caused by the currents running to the bubanana input connectors and banana our compatible with GN610B/GN611B acquisi	n to reduce inaccuracy rden resistor. Using tput pins. Directly	Ordered from custom systems <sup>(1)</sup>

(1) Contact custom systems at: <a href="mailto:customsystems@hbm.com">customsystems@hbm.com</a>
Request quote/information for special products for GEN series.

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